COMBINED DECLARATION AND POWER OF ATTORNEY FOR PATENT APPLICATION

As a below-named inventor, I hereby declare that: My residence, post office and citizenship are as stated below next to my name.

I believe I am the original, first and sole inventor (if only one name is listed below), or an original, first and joint inventor (if plural names are listed below), of the subject matter which is claimed and for which a patent is sought on the invention

entitled: HIGH ENERGY ESD STRUCTURE AND METHOD the specification of which is attached hereto unless the following box is checked: Application was filed on as Application No. and was amended on I hereby state that I have reviewed and understand the contents of the above identified specification, including the claims, as amended by any amendment referred to above. I acknowledge the duty to disclose information which is material to the examination of this application in accordance with Title 37, Code of Federal Regulations, §1.56. I hereby claim foreign priority benefits under Title 35, United States Code, § 119(a)-(d) of any foreign application(s) for patent or inventor's certificate listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed. Prior Foreign Application(s) Priority Claimed ___ Yes ___ No (Number) (Country) (Filed) I hereby claim the benefit under Title 35, United States Code, § 119(e) of any United States provisional application(s) listed below. Application No. File date

I hereby claim the benefit under Title 35, United States Code, § 120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code, § 112, I acknowledge the duty to disclose information which is material to patentability as defined in Title 37, Code of Federal Regulations, § 1.56 which became available between the filing date of the prior application and the national or PCT international filing date of this application.

CITIZENSHIP: USA

POST OFFICE ADDRESS: Same as above

(Application Number) (Filing Date) (Status - patented, pending, abandoned):
I hereby appoint the following attorney(s) and/or agent(s) to prosecute this application and to transact all business in the U.S. Patent and Trademark Office connected therewith:
Address all telephone calls to Mr. Robert F. Hightower at (602) 244-5603; facsimile Number (602) 244-3169.
Address all correspondence to Mr. Jerry Chruma, Semiconductor Components Industries, L.L.C., Patent Administration Dept - MD/A700, P.O. Box 62890, Phoenix, Arizona 85082-2890.
I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.
FULL NAME OF FIRST INVENTOR: Peter J. Zdebel
INVENTOR SIGNATURE: Place Jack J. Solo Com. DATE: Dec 29, 2003 RESIDENCE: 10048 CIRCLEVIEW DRIVE, AUSTIN, TEXAS USA 78733
CITIZENSHIP: GERMANY POST OFFICE ADDRESS: Same as above
FULL NAME OF SECOND INVENTOR (if any): Diann Michelle Dow
INVENTOR SIGNATURE: Dean Middle (by DATE: Oelmer 29, 2003) RESIDENCE: 3409 Lost Oasis Hollow

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